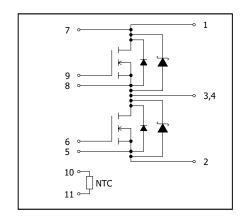
Application

- · Motor drive
- · Inverter, Converter
- · Photovoltaics, wind power generation.
- · Induction heating equipment.

Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

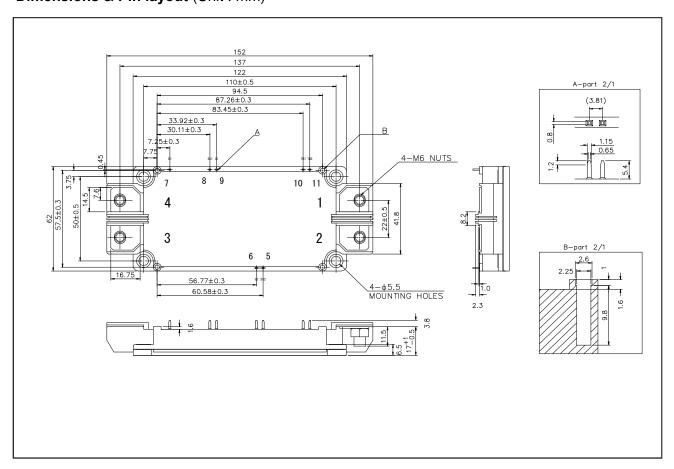
●Circuit diagram



Construction

This product is a half bridge module consisting of SiC-UMOSFET and SiC-SBD from ROHM.

●Dimensions & Pin layout (Unit : mm)

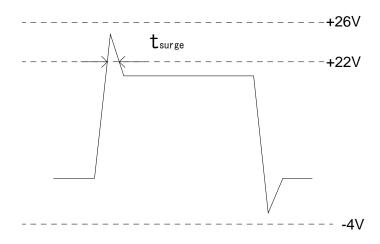


●Absolute maximum ratings (T_j = 25°C)

Parameter	Symbol	Conditions	Limit	Unit	
Drain-source voltage	V_{DSS}	G-S short	1200		
Gate-source voltage(+)	V		22	V	
Gate-source voltage(-)	V_{GSS}	D-S short	-4		
G - S Voltage (t _{surge} <300nsec)	$V_{GSSsurge}$		-4 to 26		
Drain current *1	I _D	DC (T _c =60°C) V _{GS} =18V	358		
	I _D	DC (T _c =32°C) V _{GS} =18V	400] A	
	I _{DRM}	Pulse (T_c =60°C) 1ms V_{GS} =18V * ²	800		
Source current *1	I _S	DC (T _c =60°C) V _{GS} =18V	358		
	Is	DC (T _c =32°C) V _{GS} =18V	400	A	
	I _S	DC (T _c =60°C) V _{GS} =0V	260		
	I _{SRM}	Pulse (Tc=60°C) 1ms V _{GS} =18V * ²	800		
	I _{SRM}	Pulse (Tc=60°C) 10μs V _{GS} =0V * ²	800		
Total power disspation *3	Ptot	T _c =25°C	1570	W	
Max Junction Temperature	T _{jmax}		175		
Junction temperature	T _{jop}		-40 to150	°C	
Storage temperature	T _{stg}		-40 to125		
Isolation voltage	Visol	Terminals to baseplate, f=60Hz AC 1min.	2500	Vrms	
Mounting torque	-	Main Terminals : M6 screw	4.5	N · m	
		Mounting to heat shink: M5 screw	3.5		

^(*1) Case temperature (T_c) is defined on the surface of base plate just under the chips.

●Example of acceptable V_{GS} waveform



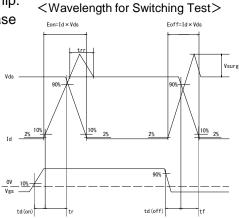
^(*2) Repetition rate should be kept within the range where temperature rise if die should not exceed T_{i max.}

^(*3) T_j is less than 175°C

●Electrical characteristics (T_i=25°C)

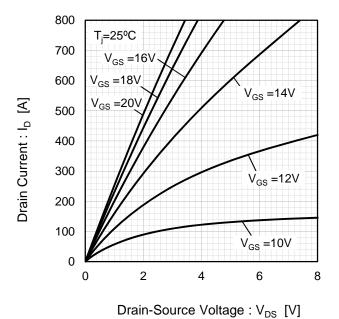
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit			
Static drain-source on-state voltage	V _{DS(on)}	I _D =400A, V _{GS} =18V	T _j =25°C	-	1.8	2.5	V			
			T _j =125°C	•	2.6	-				
			T _j =150°C	•	3.0	4.5				
Drain cutoff current	I _{DSS}	V _{DS} =1200V, V _{GS} =0V		-	-	2.4	mA			
Souce-Drain Voltage	V_{SD}	V _{GS} =0V, I _S =400A	T _j =25°C	1	2.1	2.6	V			
			T _j =125°C	ı	2.7	-				
			T _j =150°C	-	2.8	4.8				
		V _{GS} =18V, I _S =400A	T _j =25°C	1	1.3	-	V			
			T _j =125°C	ı	1.8	-				
			T _j =150°C	1	1.9	-				
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} =10V, I_{D} =109.2mA	V _{DS} =10V, I _D =109.2mA		-	5.6	V			
Gate-source leakage current	I _{GSS}	V _{GS} =22V, V _{DS} =0V		1	•	0.5	^			
		$V_{GS} = -4V, V_{DS} = 0V$		-0.5	-	-	μА			
Switching characteristics	t _{d(on)}	$V_{GS(on)}$ =18V, $V_{GS(off)}$ = -2V *4		1	45	-	ns			
	t _r	V _{DS} =600V		ı	55	-				
	t _{rr}	I _D =400A	-	45	-					
	$t_{d(off)}$	$R_{G(on)}$ =2.2 Ω , $R_{G(off)}$ =2.2 Ω inductive load		ı	240	-				
	t _f			1	55	-				
Input capacitance	Ciss	V_{DS} =10V, V_{GS} =0V,200	1	17	-	nF				
Gate Registance	R_{Gint}	T _j =25°C	ı	2.4	-	Ω				
NTC Rated Resistance	R25		1	5.0	-	kΩ				
NTC B Value	B _{50/25}		1	3370	-	K				
Stray Inductance	Ls			ı	10.5	-	nΗ			
Creepage Distance	-	Terminal to heat sink		-	16.7	-	mm			
		Terminal to terminal		ı	16.7	-	mm			
Clearance Distance	-	Terminal to heat sink		ı	12.0	-	mm			
		Terminal to terminal		-	11.0	-	mm			
Junction-to-case thermal resistance	R _{th} (j-c)	UMOS (1/2 module) *5		1	-	96	°C/kW			
		SBD (1/2 module) *5		1	-	127				
Case-to-heat sink Thermal resistance	R _{th} (c-f)	Case to heat sink, per			15	-	C/KVV			
		Thermal grease applie	ed * ⁶	-	10					
(*4) In order to prevent self turn on, it is recommended to apply negative gate higs										

- (*4) In order to prevent self turn-on, it is recommended to apply negative gate bias.
- (*5) Measurement of Tc is to be done at the point just under the chip.
- (*6) Typical value is measured by using thermally conductive grease of $\lambda=0.9W/(m\cdot K)$.
- (*7) SiC devices have lower short cuicuit withstand capability due to high current density. Please be advised to pay careful attention to short cuicuit accident and try to adjust protection time to shutdown them as short as possible.
- (*8) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be dameged, please replace such Product with a new one.

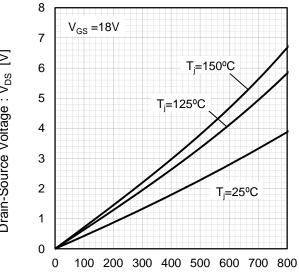


● Electrical characteristic curves (Typical)

Fig.1 Typical Output Characteristics [T_i =25°C] Fig.2 Drain-Source Voltage vs. Drain Current



Drain-Source Voltage: V_{DS} [V]



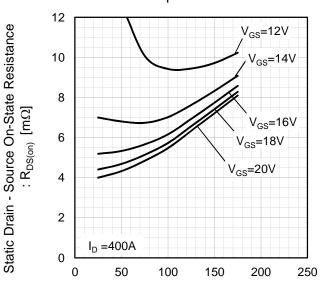
Drain Current : I_D [A]

Fig.3 Drain-Source Voltage vs. Gate-Source Voltage [T_i=25°C] 5 T_i=25°C

Drain-Source Voltage: V_{DS} [V] 4 3 I_D=400A 2 I_D=300A I_D=200A 1 $I_{D} = 100A$ 0 12 16 18 20 22 24 14

Gate-Source Voltage: V_{GS} [V]

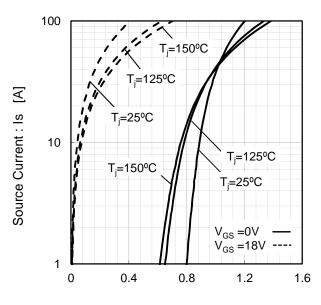
Fig.4 Static Drain - Source On-State Resistance vs. Junction Temperature



Junction Temperature : T_i [°C]

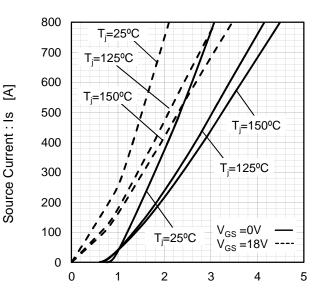
● Electrical characteristic curves (Typical)

Fig.5 Forward characteristic of Diode



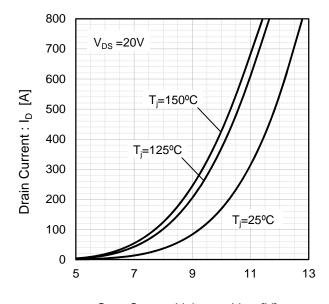
Source-Drain Voltage: V_{SD} [V]

Fig.6 Forward characteristic of Diode



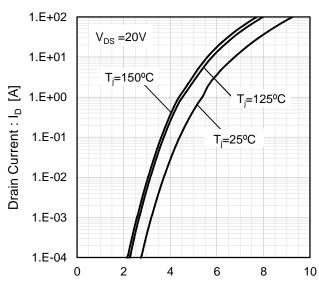
Source-Drain Voltage: V_{SD} [V]

Fig.7 Drain Current vs. Gate-Source Voltage



Gate-Source Voltage : V_{GS} [V]

Fig.8 Drain Current vs. Gate-Source Voltage



Gate-Source Voltage : V_{GS} [V]

• Electrical characteristic curves (Typical)

Fig.9 Switching Characteristics [T_i=25°C]

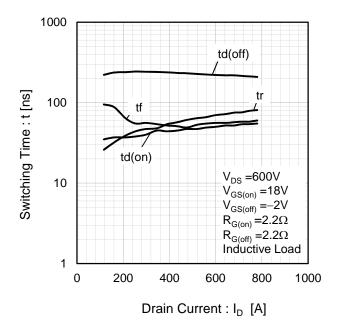


Fig.10 Switching Characteristics [T_i=125°C]

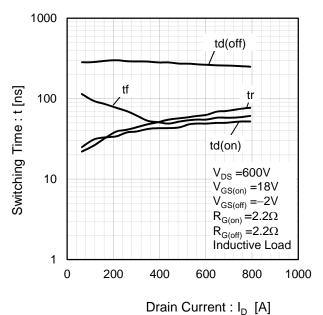


Fig.11 Switching Characteristics [T_i=150°C]

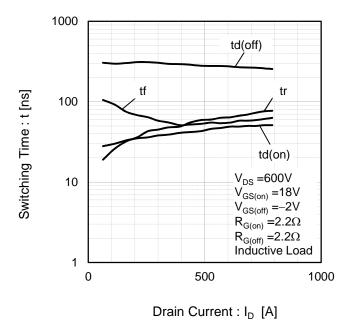
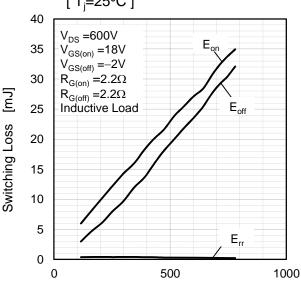
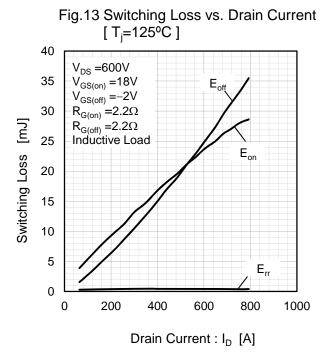
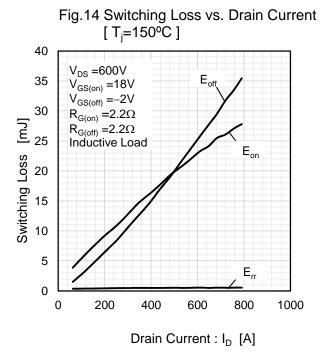


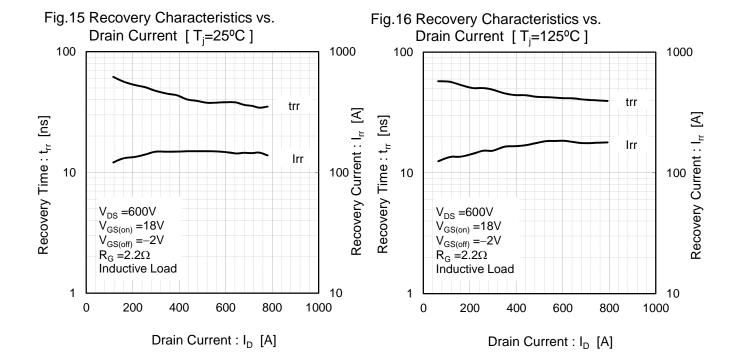
Fig.12 Switching Loss vs. Drain Current [$T_i=25^{\circ}C$]



●Electrical characteristic curves (Typical)







●Electrical characteristic curves (Typical)

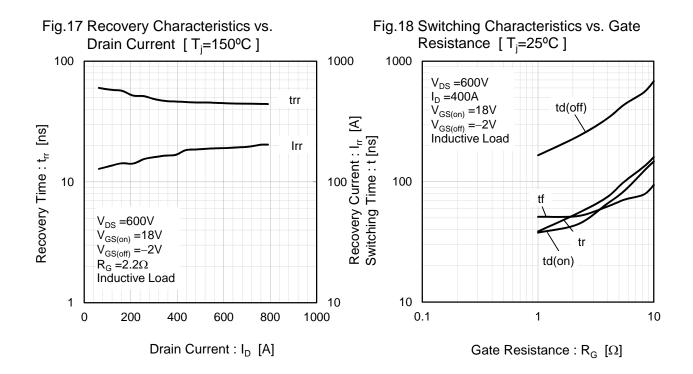


Fig.19 Switching Characteristics vs. Gate Resistance [T_i=125°C]

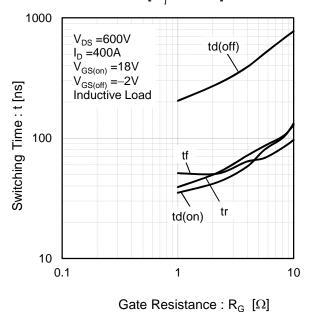
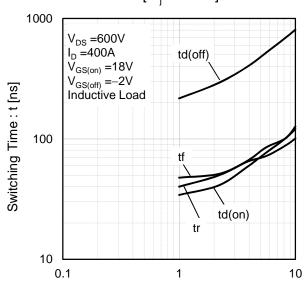


Fig.20 Switching Characteristics vs. Gate Resistance [$T_i=150$ °C]



Gate Resistance : R_G [Ω]

10

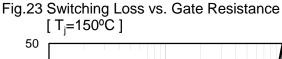
●Electrical characteristic curves (Typical)

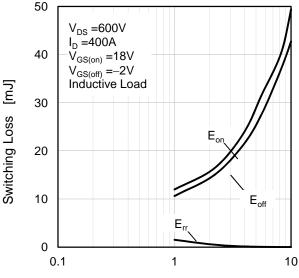
Fig.21 Switching Loss vs. Gate Resistance $[T_i=25^{\circ}C]$ 60 V_{DS} =600V $I_{D} = 400A$ 50 $V_{GS(off)} = 18V$ $V_{GS(off)} = -2V$ Inductive Load Switching Loss [mJ] 40 30 20 $\mathsf{E}_{\mathsf{off}}$ 10 0 0.1 10

Fig.22 Switching Loss vs. Gate Resistance $[T_j=125^{\circ}C]$ 60 $V_{DS}=600V$ $I_{D}=400A$ $V_{GS(on)}=18V$ $V_{GS(off)}=-2V$ $I_{D}=400A$ $I_{D}=40$

Gate Resistance : R_G [Ω]

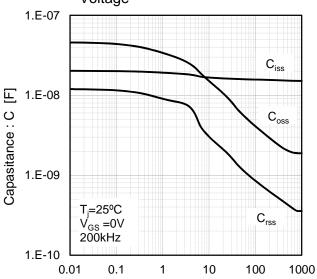
Gate Resistance : R_G [Ω]





Gate Resistance : R_G [Ω]

Fig.24 Typical Capacitance vs. Drain-Source Voltage



Drain-Source Voltage : V_{DS} [V]

Switching Loss [mJ]

0.1

●Electrical characteristic curves (Typical)

Fig.25 Gate Charge Characteristics

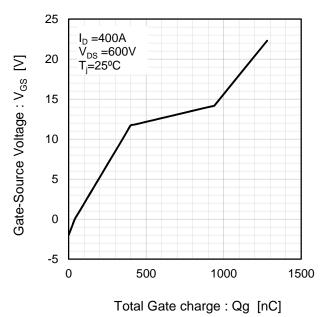


Fig.26 Normalized Transient Thermal Impedance 1 Normalized Transient Thermal Impedance: Zth 0.1 Single Pulse $T_c=25$ °C Per unit base DMOS part: 96°C/kW SBD part : 127°C/kW 0.01 0.0001 0.001 0.1 0.01 1 10

Time [s]

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